IRGP4640PbF
IRGP4640-EPbF

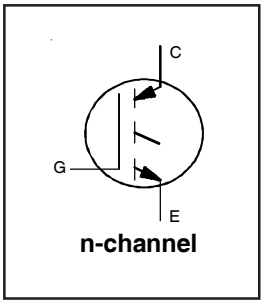
INSULATED GATE BIPOLAR TRANSISTOR

V_{CES} = 600V

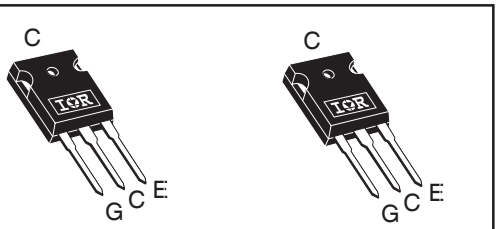
I_C = 40A, T_C = 100°C

$t_{SC} \geq$ 5µs, $T_{J(max)}$ = 175°C

$V_{CE(on)}$ typ. = 1.60V @ I_C = 24A



n-channel



TO-247AC
IRGP4640PbF

TO-247AD
IRGP4640-EP

G	C	E
Gate	Collector	Emitter

Applications
- Inverters
- UPS
- Welding

Features	→	Benefits
Low $V_{CE(ON)}$ and Switching Losses		High efficiency in a wide range of applications and switching frequencies
Square RBSOA and Maximum Junction Temperature 175°C		Improved reliability due to rugged hard switching performance and higher power capability
Positive $V_{CE\ (ON)}$ Temperature Coefficient		Excellent current sharing in parallel operation
5µs short circuit SOA		Enables short circuit protection scheme
Lead-Free, RoHS compliant		Environmentally friendly

Base part number	Package Type	Standard Pack		Orderable part number
		Form	Quantity	
IRGP4640PbF	TO-247AC	Tube	25	IRGP4640PbF
IRGP4640-EPbF	TO-247AD	Tube	25	IRGP4640-EPbF

Absolute Maximum Ratings

	Parameter	Max.	Units
V_{CES}	Collector-to-Emitter Voltage	600	V
I_C @ T_C = 25°C	Continuous Collector Current	65	A
I_C @ T_C = 100°C	Continuous Collector Current	40	
I_{CM}	Pulse Collector Current, V_{GE} = 15V ①	72	
I_{LM}	Clamped Inductive Load Current, V_{GE} = 20V ②	96	
V_{GE}	Continuous Gate-to-Emitter Voltage	±20	V
	Transient Gate-to-Emitter Voltage	±30	
P_D @ T_C = 25°C	Maximum Power Dissipation	250	W
P_D @ T_C = 100°C	Maximum Power Dissipation	125	
T_J T_{STG}	Operating Junction and Storage Temperature Range	-40 to +175	°C
	Soldering Temperature, for 10 sec.	300 (0.063 in. (1.6mm) from case)	
	Mounting Torque, 6-32 or M3 Screw	10 lbf·in (1.1 N·m)	

Thermal Resistance

	Parameter	Min.	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case ③	—	—	0.60	°C/W
$R_{\theta CS}$	Case-to-Sink (flat, greased surface)	—	0.24	—	
$R_{\theta JA}$	Junction-to-Ambient (typical socket mount)	—	—	40	

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Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Conditions
$V_{(BR)CES}$	Collector-to-Emitter Breakdown Voltage	600	—	—	V	V_{GE} = 0V, I_C = 100µA ④
$\Delta V_{(BR)CES}/\Delta T_J$	Temperature Coeff. of Breakdown Voltage	—	0.30	—	V/°C	V_{GE} = 0V, I_C = 1mA (25°C-175°C)
$V_{CE(on)}$	Collector-to-Emitter Saturation Voltage	—	1.60	1.90	V	I_C = 24A, V_{GE} = 15V, T_J = 25°C
		—	2.00	—		I_C = 24A, V_{GE} = 15V, T_J = 175°C
$V_{GE(th)}$	Gate Threshold Voltage	4.0	—	6.5	V	V_{CE} = V_{GE}, I_C = 700µA
$\Delta V_{GE(th)}/\Delta T_J$	Threshold Voltage temp. coefficient	—	-18	—	mV/°C	V_{CE} = V_{GE}, I_C = 1.0mA (25°C - 175°C)
gfe	Forward Transconductance	—	17	—	S	V_{CE} = 50V, I_C = 24A, PW = 80µs
I_{CES}	Collector-to-Emitter Leakage Current	—	1.0	20	µA	V_{GE} = 0V, V_{CE} = 600V
		—	600	—		V_{GE} = 0V, V_{CE} = 600V, T_J = 175°C
I_{GES}	Gate-to-Emitter Leakage Current	—	—	±100	nA	V_{GE} = ±20V

Switching Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.⑤	Units	Conditions
Q_g	Total Gate Charge (turn-on)	—	50	75	nC	I_C = 24A
Q_{ge}	Gate-to-Emitter Charge (turn-on)	—	15	20		V_{GE} = 15V
Q_{gc}	Gate-to-Collector Charge (turn-on)	—	20	30		V_{CC} = 400V
E_{on}	Turn-On Switching Loss	—	0.1	0.2	mJ	
E_{off}	Turn-Off Switching Loss	—	0.6	0.7		
E_{total}	Total Switching Loss	—	0.7	0.9		I_C = 24A, V_{CC} = 400V, V_{GE} = 15V ⑥
$t_{d(on)}$	Turn-On delay time	—	40	55	ns	R_G = 10Ω, T_J = 25°C
t_r	Rise time	—	20	30		Energy losses include tail & diode reverse recovery
$t_{d(off)}$	Turn-Off delay time	—	105	115		
t_f	Fall time	—	30	40		
E_{on}	Turn-On Switching Loss	—	0.4	—	mJ	
E_{off}	Turn-Off Switching Loss	—	0.85	—		
E_{total}	Total Switching Loss	—	1.25	—		I_C = 24A, V_{CC} = 400V, V_{GE}=15V ⑥
$t_{d(on)}$	Turn-On delay time	—	40	—	ns	R_G=10Ω, T_J = 175°C
t_r	Rise time	—	25	—		Energy losses include tail & diode reverse recovery
$t_{d(off)}$	Turn-Off delay time	—	125	—		
t_f	Fall time	—	40	—		
C_{ies}	Input Capacitance	—	1490	—	pF	V_{GE} = 0V
C_{oes}	Output Capacitance	—	130	—		V_{CC} = 30V
C_{res}	Reverse Transfer Capacitance	—	45	—		f = 1.0Mhz
RBSOA	Reverse Bias Safe Operating Area	FULL SQUARE				T_J = 175°C, I_C = 96A V_{CC} = 480V, Vp =600V Rg = 10Ω, V_{GE} = +20V to 0V
SCSOA	Short Circuit Safe Operating Area	5	—	—	µs	V_{CC} = 400V, Vp =600V Rg = 10Ω, V_{GE} = +15V to 0V

Notes:

① Pulse width limited by max. junction temperature.

② V_{CC} = 80% (V_{CES}), V_{GE} = 20V, L = 100µH, R_G = 10Ω.

③ R_θ is measured at T_J of approximately 90°C.

④ Refer to AN-1086 for guidelines for measuring $V_{(BR)CES}$ safely.

⑤ Maximum limits are based on statistical sample size characterization.

⑥ Values are influenced by parasitic L and C in measurement.

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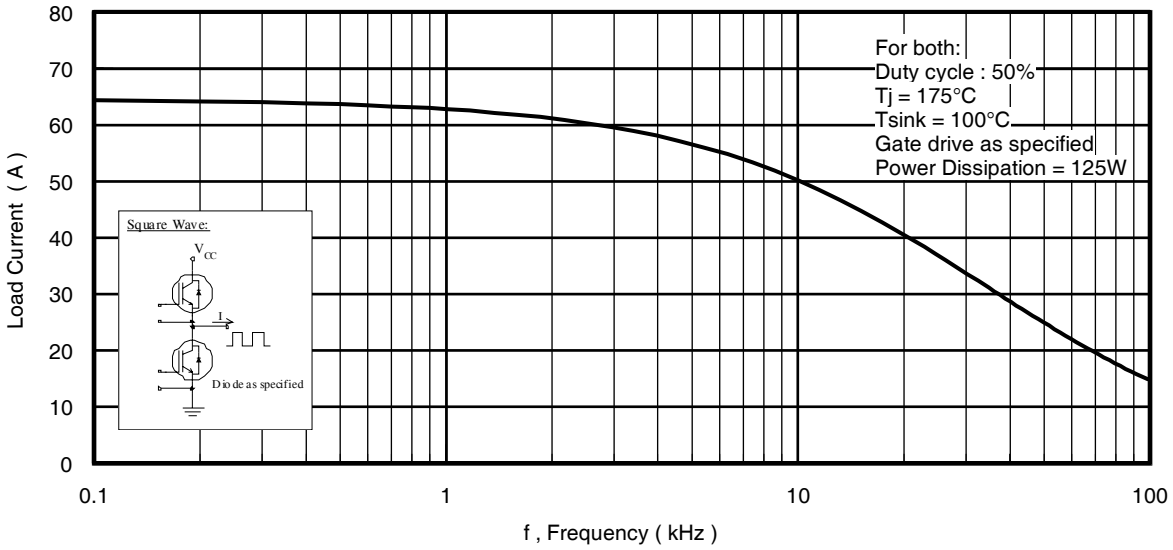


Fig. 1 - Typical Load Current vs. Frequency
(Load Current = IRMS of fundamental)

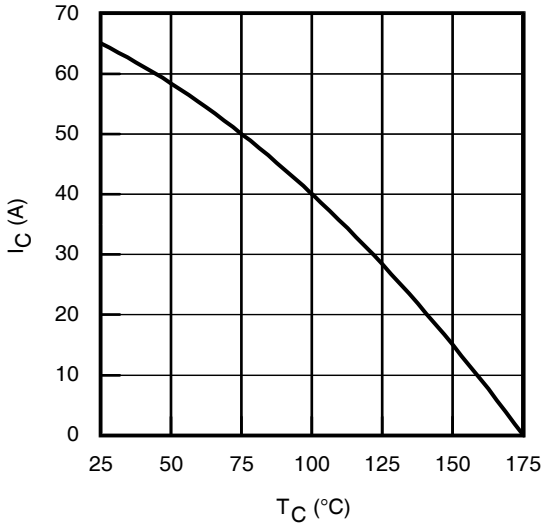


Fig. 2 - Maximum DC Collector Current vs. Case Temperature

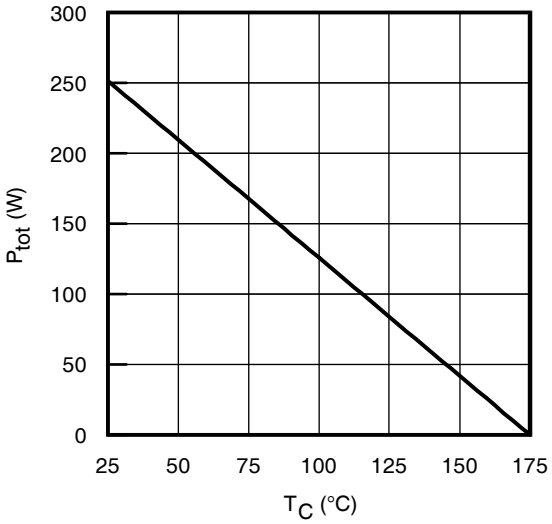


Fig. 3 - Power Dissipation vs. Case Temperature

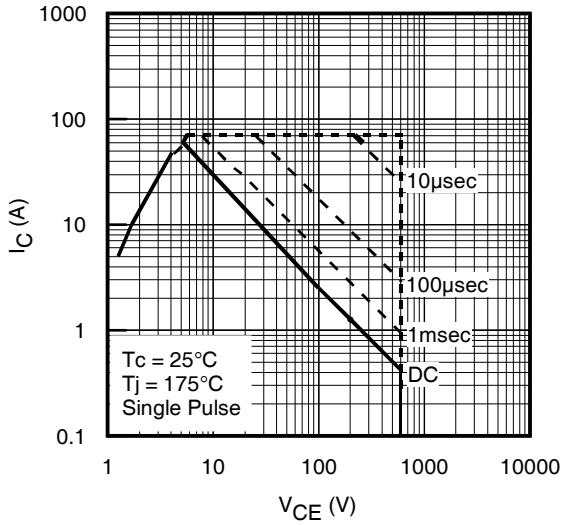


Fig. 4 - Forward SOA
T_C = 25°C, $T_J \leq$ 175°C; V_{GE} =15V

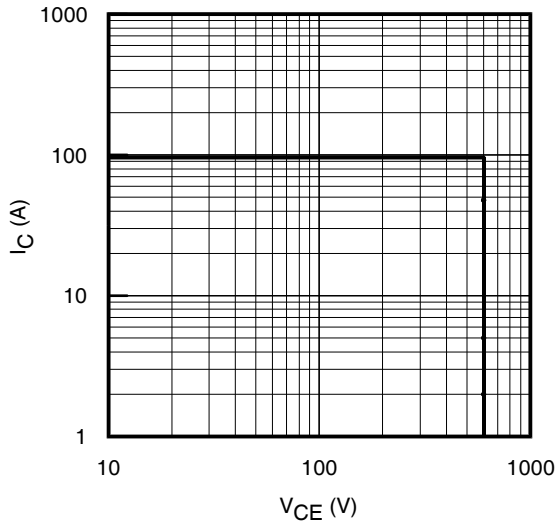


Fig. 5 - Reverse Bias SOA
T_J = 175°C; V_{GE} =20V

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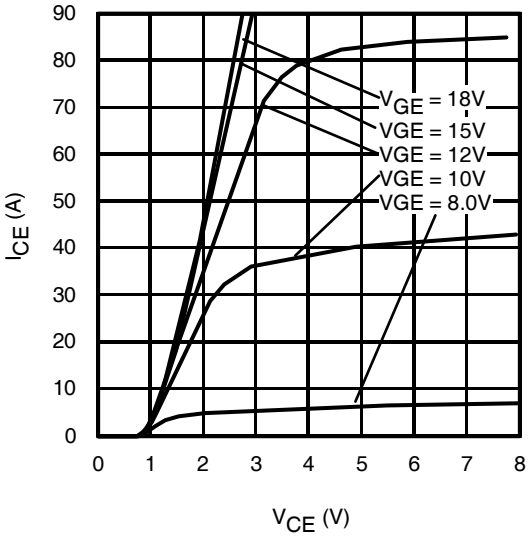


Fig. 6 - Typ. IGBT Output Characteristics
T_J = -40°C; tp = 80µs

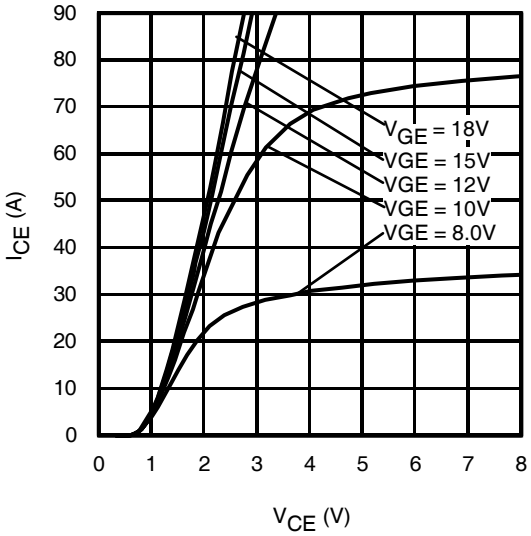


Fig. 7 - Typ. IGBT Output Characteristics
T_J = 25°C; tp = 80µs

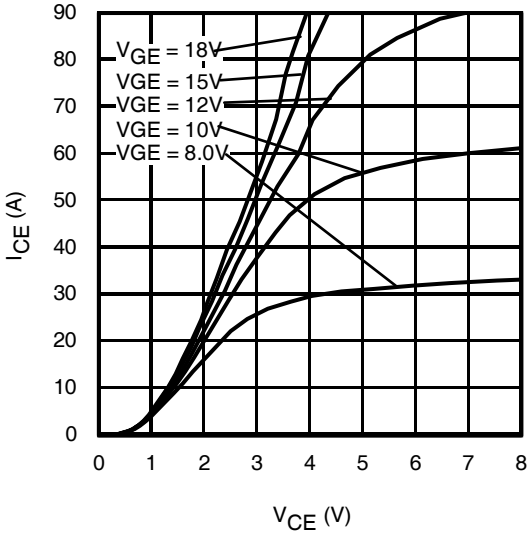


Fig. 8 - Typ. IGBT Output Characteristics
T_J = 175°C; tp = 80µs

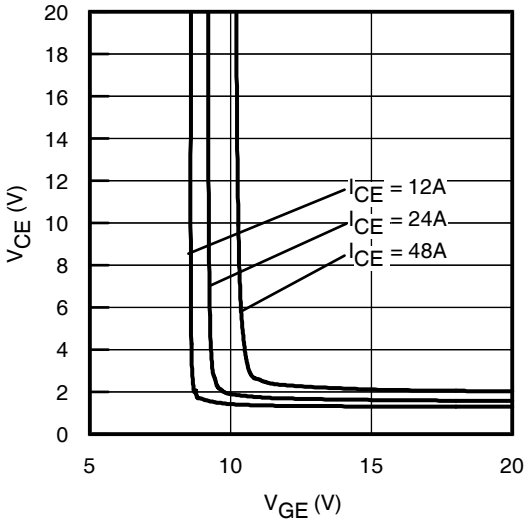


Fig. 9 - Typical V_{CE} vs. V_{GE}
T_J = -40°C

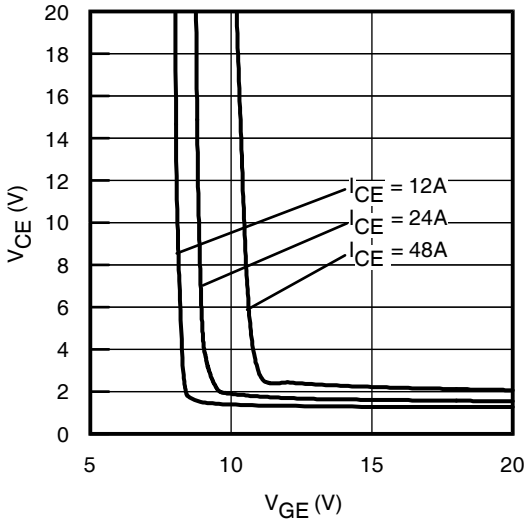


Fig. 10 - Typical V_{CE} vs. V_{GE}
T_J = 25°C

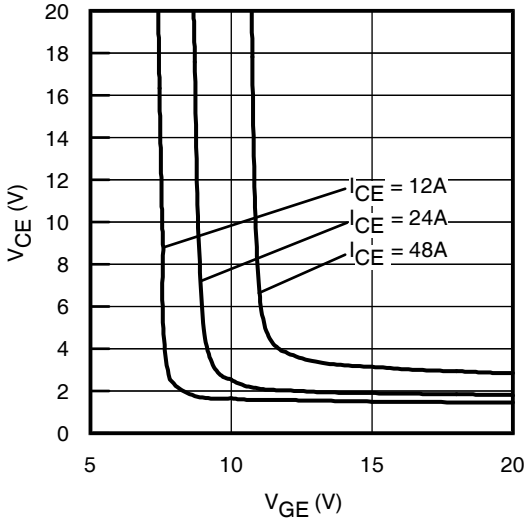


Fig. 11 - Typical V_{CE} vs. V_{GE}
T_J = 175°C

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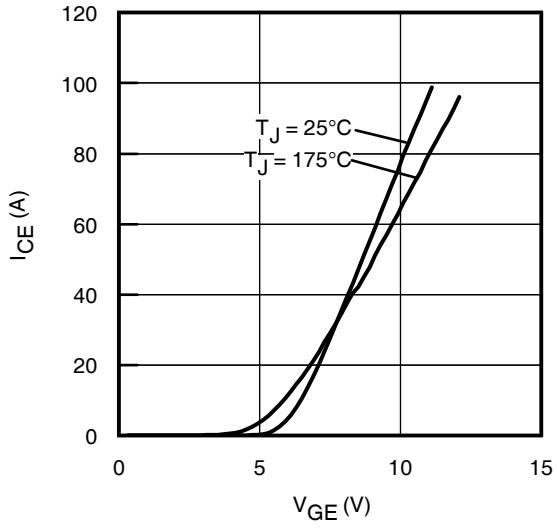


Fig. 12 - Typ. Transfer Characteristics
V_{CE} = 50V; tp = 10µs

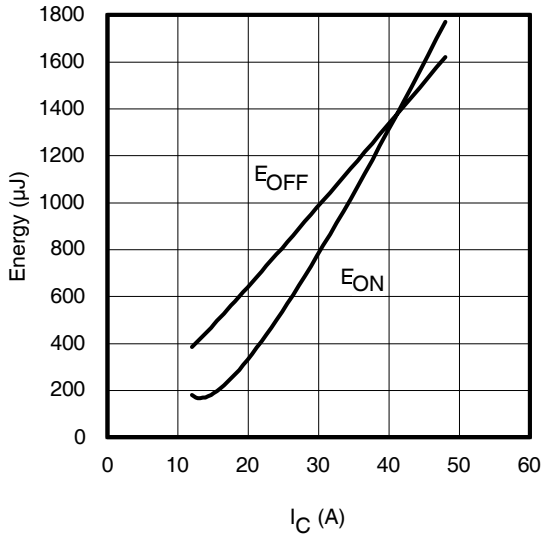


Fig. 13 - Typ. Energy Loss vs. I_C
T_J = 175°C; L = 200µH; V_{CE} = 400V, R_G = 10Ω; V_{GE} = 15V

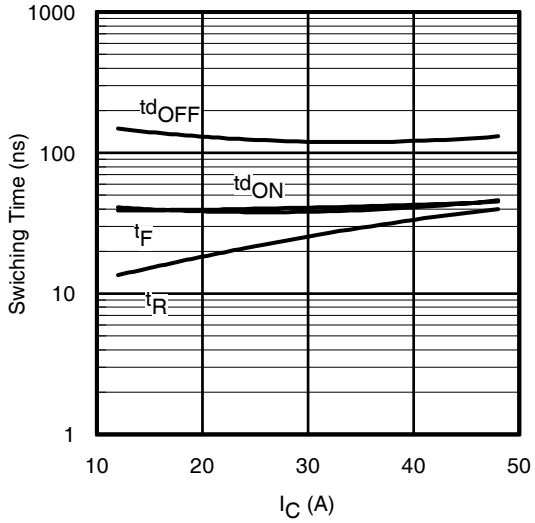


Fig. 14 - Typ. Switching Time vs. I_C
T_J = 175°C; L = 200µH; V_{CE} = 400V, R_G = 10Ω; V_{GE} = 15V

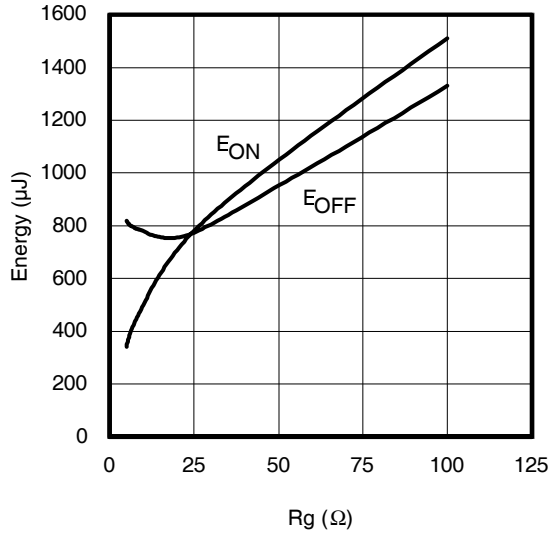


Fig. 15 - Typ. Energy Loss vs. R_G
T_J = 175°C; L = 200µH; V_{CE} = 400V, I_{CE} = 24A; V_{GE} = 15V

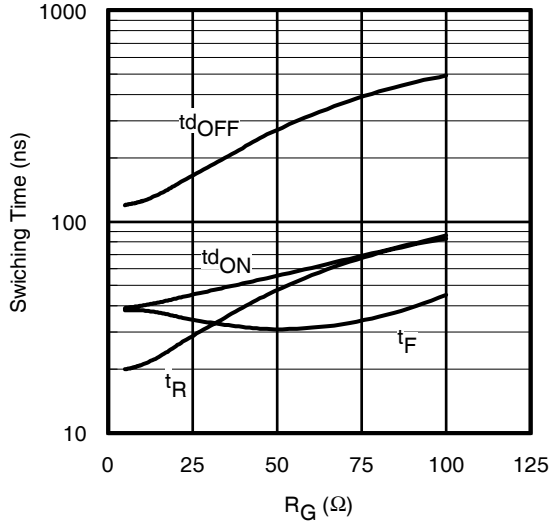


Fig. 16 - Typ. Switching Time vs. R_G
T_J = 175°C; L = 200µH; V_{CE} = 400V, I_{CE} = 24A; V_{GE} = 15V

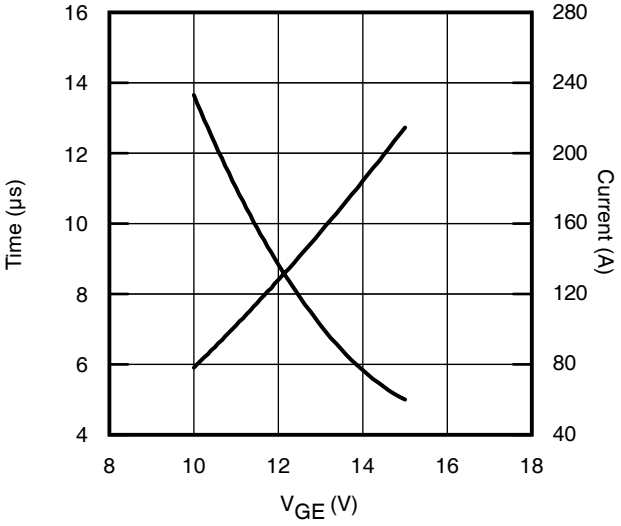


Fig. 17 - V_{GE} vs. Short Circuit Time
V_{CC} = 400V; T_C = 25°C

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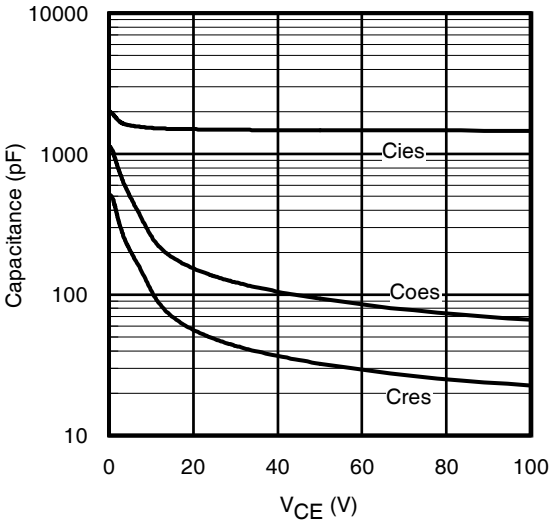


Fig. 18 - Typ. Capacitance vs. V_{CE}
V_{GE}= 0V; f = 1MHz

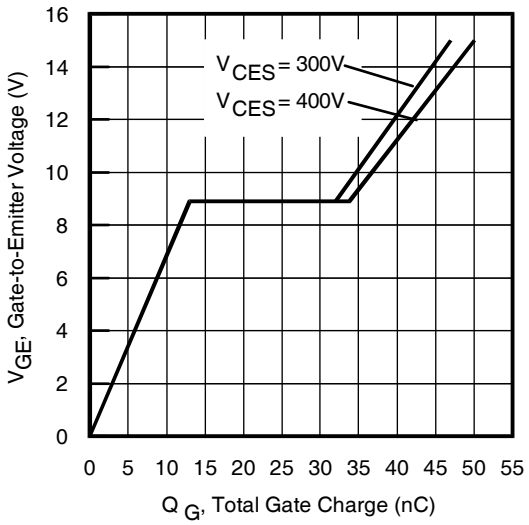


Fig. 19 - Typical Gate Charge vs. V_{GE}
I_{CE} = 24A; L = 600µH

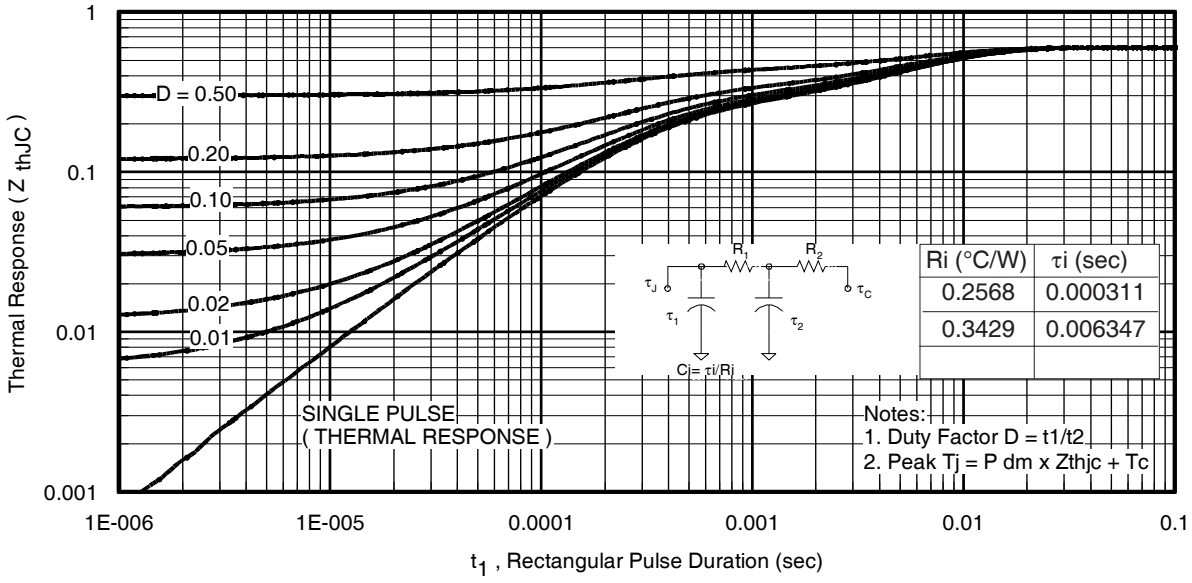


Fig 20. Maximum Transient Thermal Impedance, Junction-to-Case

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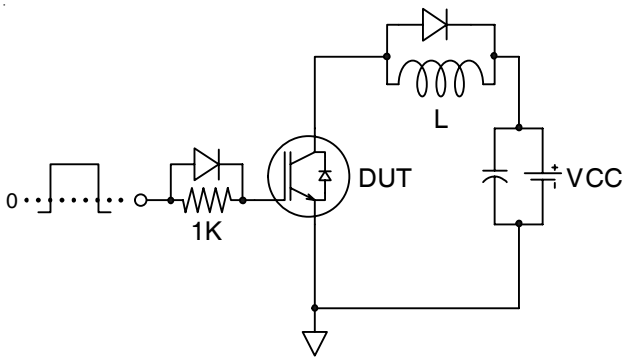


Fig.C.T.1 - Gate Charge Circuit (turn-off)

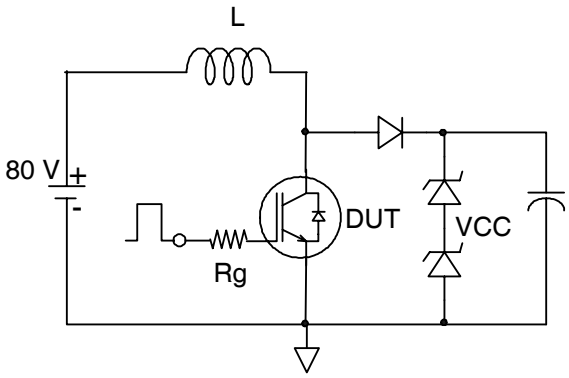


Fig.C.T.2 - RBSOA Circuit

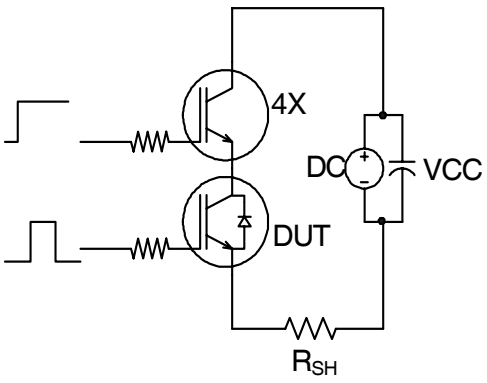


Fig.C.T.3 - S.C. SOA Circuit

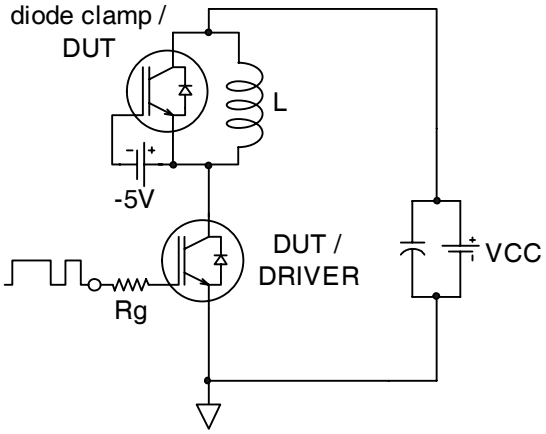


Fig.C.T.4 - Switching Loss Circuit

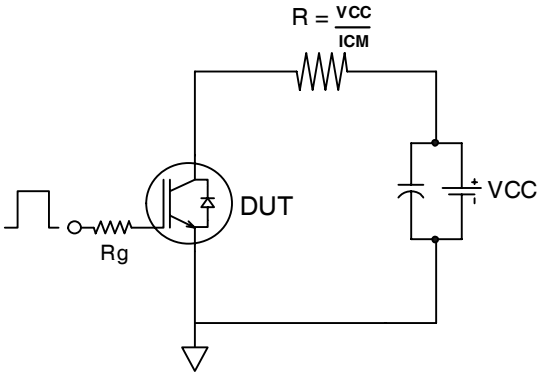


Fig.C.T.5 - Resistive Load Circuit

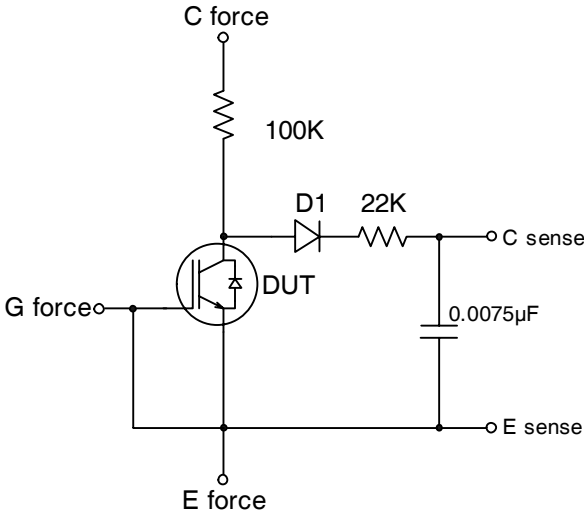


Fig.C.T.6 - BVCES Filter Circuit

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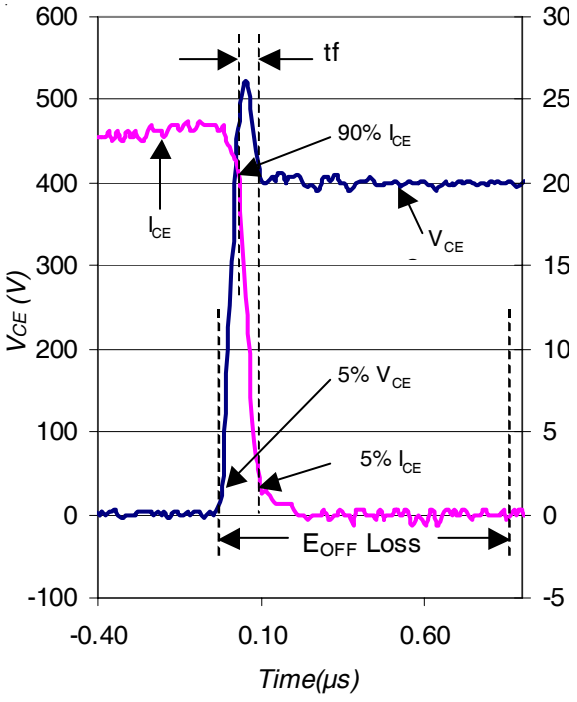


Fig. WF1 - Typ. Turn-off Loss Waveform
@ T_J = 175°C using Fig. CT.4

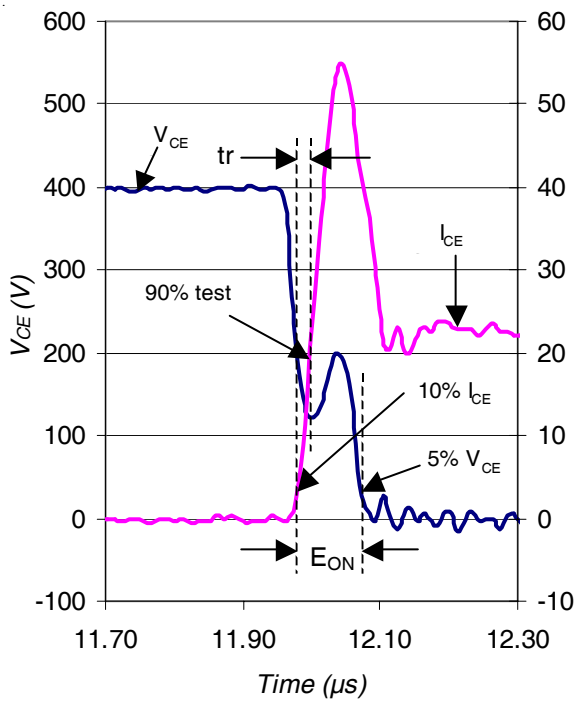


Fig. WF2 - Typ. Turn-on Loss Waveform
@ T_J = 175°C using Fig. CT.4

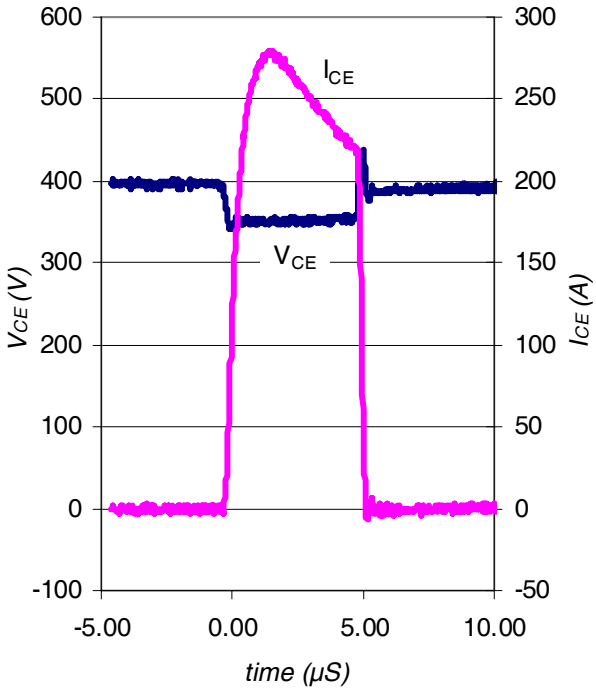
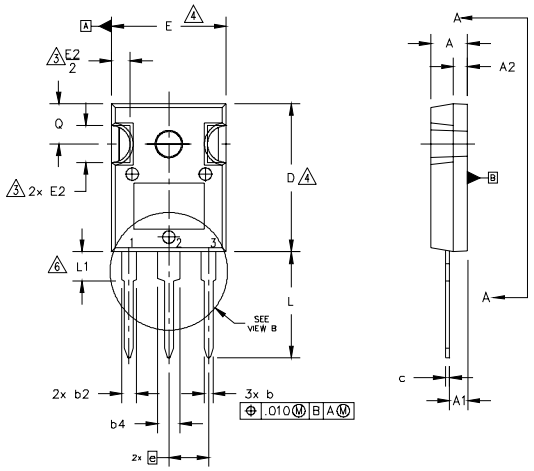


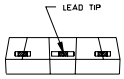
Fig. WF4 - Typ. S.C. Waveform
@ T_J = 25°C using Fig. CT.3

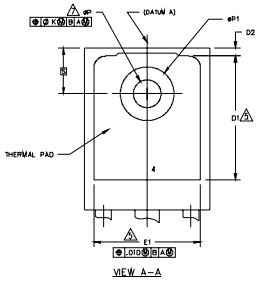
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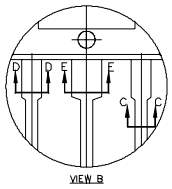
TO-247AC Package Outline

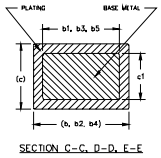
Dimensions are shown in millimeters (inches)











NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M 1994.
2. DIMENSIONS ARE SHOWN IN INCHES.
3. CONTOUR OF SLOT OPTIONAL.
4. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005" (0.127) PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
5. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS D1 & E1.
6. LEAD FINISH UNCONTROLLED IN L1.
7. øP TO HAVE A MAXIMUM DRAFT ANGLE OF 1.5 ° TO THE TOP OF THE PART WITH A MAXIMUM HOLE DIAMETER OF .154 INCH.
8. OUTLINE CONFORMS TO JEDEC OUTLINE TO-247AC .

SYMBOL	DIMENSIONS				NOTES
	INCHES		MILLIMETERS		
	MIN.	MAX.	MIN.	MAX.	
A	.183	.209	4.65	5.31	
A1	.087	.102	2.21	2.59	
A2	.059	.098	1.50	2.49	
b	.039	.055	0.99	1.40	
b1	.039	.053	0.99	1.35	
b2	.065	.094	1.65	2.39	
b3	.065	.092	1.65	2.34	
b4	.102	.135	2.59	3.43	
b5	.102	.133	2.59	3.38	
c	.015	.035	0.38	0.89	
c1	.015	.033	0.38	0.84	
D	.776	.815	19.71	20.70	4
D1	.515	–	13.08	–	5
D2	.020	.053	0.51	1.35	
E	.602	.625	15.29	15.87	4
E1	.530	–	13.46	–	
E2	.178	.216	4.52	5.49	
e	.215 BSC		5.46 BSC		
øk	.010		0.25		
L	.559	.634	14.20	16.10	
L1	.146	.169	3.71	4.29	
øP	.140	.144	3.56	3.66	
øP1	–	.291	–	7.39	
Q	.209	.224	5.31	5.69	
S	.217 BSC		5.51 BSC		

LEAD ASSIGNMENTS

HEXFET

1.– GATE
2.– DRAIN
3.– SOURCE
4.– DRAIN

IGBTs, CoPACK

1.– GATE
2.– COLLECTOR
3.– EMITTER
4.– COLLECTOR

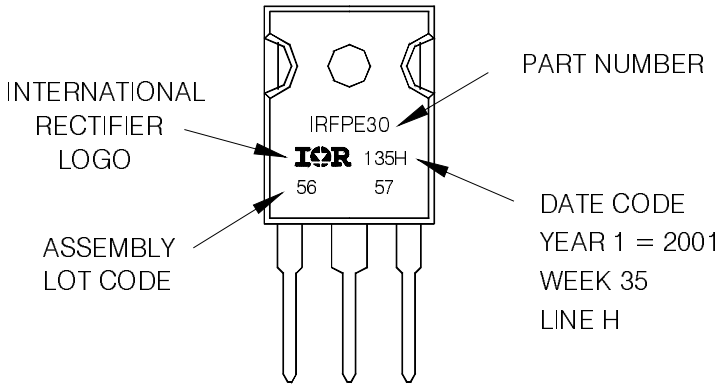
DIODES

1.– ANODE/OPEN
2.– CATHODE
3.– ANODE

TO-247AC Part Marking Information

EXAMPLE: THIS IS AN IRFPE30
WITH ASSEMBLY
LOT CODE 5657
ASSEMBLED ON WW 35, 2001
IN THE ASSEMBLY LINE "H"

Note: "P" in assembly line position
indicates "Lead-Free"



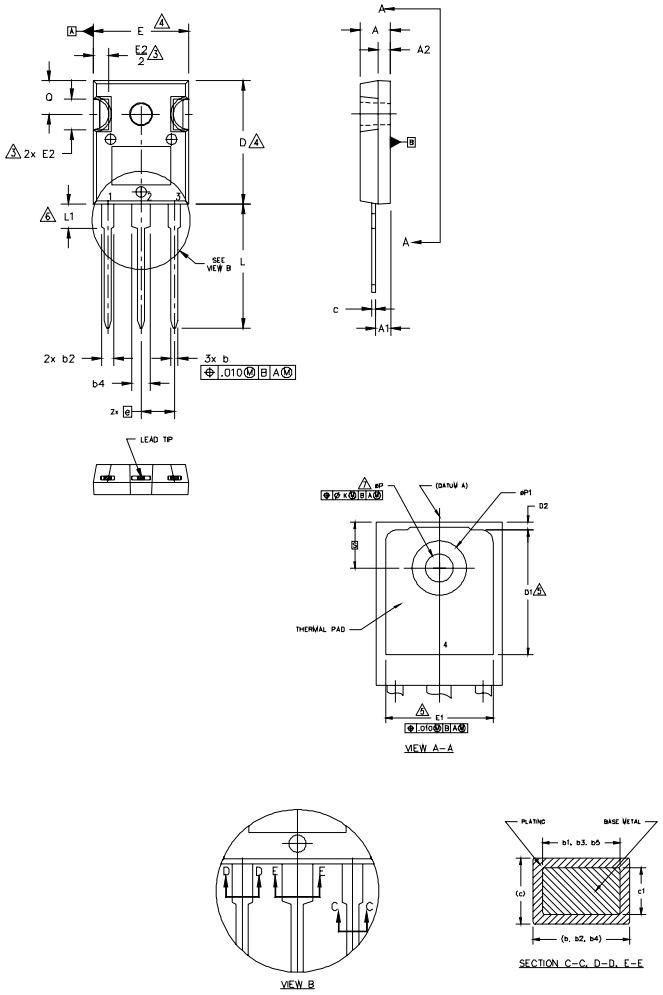
TO-247AC package is not recommended for Surface Mount Application.

Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

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TO-247AD Package Outline

Dimensions are shown in millimeters (inches)



NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M 1994.
2. DIMENSIONS ARE SHOWN IN INCHES.
3. CONTOUR OF SLOT OPTIONAL.
4. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005" (0.127) PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
5. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS D1 & E1.
6. LEAD FINISH UNCONTROLLED IN L1.
7. øP TO HAVE A MAXIMUM DRAFT ANGLE OF 1.5 ° TO THE TOP OF THE PART WITH A MAXIMUM HOLE DIAMETER OF .154 INCH.
8. OUTLINE CONFORMS TO JEDEC OUTLINE TO-247AD.

SYMBOL	DIMENSIONS				NOTES
	INCHES		MILLIMETERS		
	MIN.	MAX.	MIN.	MAX.	
A	.183	.209	4.65	5.31	
A1	.087	.102	2.21	2.59	
A2	.059	.098	1.50	2.49	
b	.039	.055	0.99	1.40	
b1	.039	.053	0.99	1.35	
b2	.065	.094	1.65	2.39	
b3	.065	.092	1.65	2.34	
b4	.102	.135	2.59	3.43	
b5	.102	.133	2.59	3.38	
c	.015	.035	0.38	0.89	
c1	.015	.033	0.38	0.84	
D	.776	.815	19.71	20.70	4
D1	.515	–	13.08	–	5
D2	.020	.053	0.51	1.35	
E	.602	.625	15.29	15.87	4
E1	.530	–	13.46	–	
E2	.178	.216	4.52	5.49	
e	.215 BSC		5.46 BSC		
øk	.010		0.25		
L	.780	.827	19.57	21.00	
L1	.146	.169	3.71	4.29	
øP	.140	.144	3.56	3.66	
øP1	–	.291	–	7.39	
Q	.209	.224	5.31	5.69	
S	.217 BSC		5.51 BSC		

LEAD ASSIGNMENTS

HEXFET

1.– GATE
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IGBTs, CoPACK

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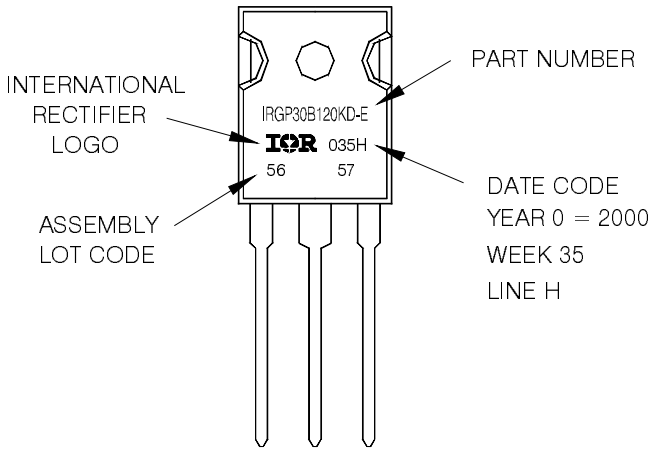
DIODES

1.– ANODE/OPEN
2.– CATHODE
3.– ANODE

TO-247AD Part Marking Information

EXAMPLE: THIS IS AN IRGP30B120KD-E
WITH ASSEMBLY
LOT CODE 5657
ASSEMBLED ON WW 35, 2000
IN THE ASSEMBLY LINE "H"

Note: "P" in assembly line position
indicates "Lead-Free"



TO-247AD package is not recommended for Surface Mount Application.

Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

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Qualification Information†

Qualification Level		Industrial (per International Rectifier's internal guidelines)	
Moisture Sensitivity Level		TO-247AC	N/A
		TO-247AD	N/A
ESD	Human Body Model	Class H1C (+/- 2000V)†† (per JEDEC JESD22-A114)	
	Charged Device Model	Class C5 (+/- 1000V)†† (per JEDEC JESD22-C101)	
RoHS Compliant		Yes	

† Qualification standards can be found at International Rectifier's web site: http://www.irf.com/product-info/reliability

†† Highest passing voltage.

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IR WORLD HEADQUARTERS: 101 N. Sepulveda Blvd., El Segundo, California 90245, USA
To contact International Rectifier, please visit http://www.irf.com/whoto-call/

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Entegreci is an online electronic components store based in Türkiye. Search by manufacturer part number to see stock, prices and datasheets for integrated circuits, microcontrollers, transistors, passive components and connectors, or request a quote for parts that are not listed.

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